

IS1, IS5, IS74
 ISD1, ISD5, ISD74
 ISQ1, ISQ5, ISQ74



ISOCOM

COMPONENTS

HIGH DENSITY PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



APPROVALS

- UL recognised, File No. E91231
 Package " FF "

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form :-
 - STD
 - G form
 - SMD approved to CECC 0080
- IS1X, IS5X, IS74X are certified to
 EN60950 by :-
 Nemko - Certificate No. P01102464

DESCRIPTION

The IS*, ISD*, ISQ* series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

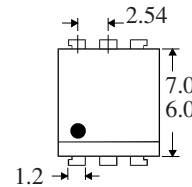
FEATURES

- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape&reel - add SMT&R after part no.
- High Isolation Voltage ($5.3kV_{RMS}$, $7.5kV_{PK}$)
- High BV_{CEO} (70V min) IS5, ISD5, ISQ5

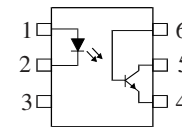
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Signal transmission between systems of different potentials and impedances

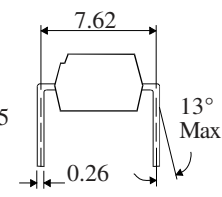
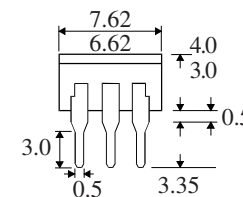
IS1
 IS5
 IS74



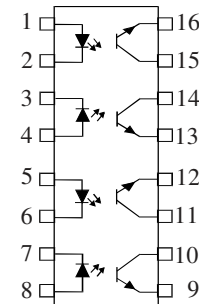
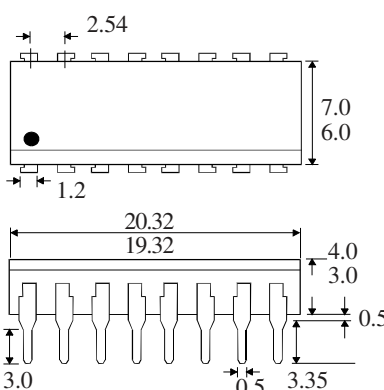
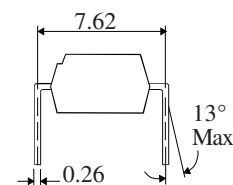
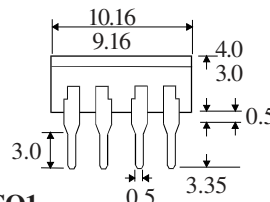
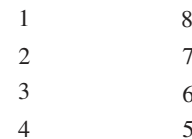
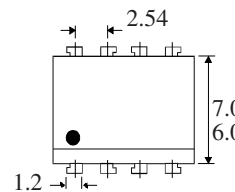
Dimensions in mm



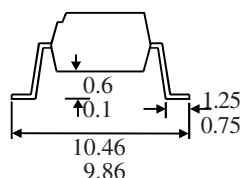
ISD1
 ISD5
 ISD74



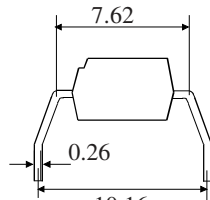
ISQ1
 ISQ5
 ISQ74



OPTION SM
 SURFACE MOUNT



OPTION G



ISOCOM COMPONENTS LTD

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 Hartlepool, Cleveland, TS25 1UD
 Tel: (01429) 863609 Fax: (01429) 863581

ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature _____ -40°C to +125°C
 Operating Temperature _____ -25°C to +100°C
 Lead Soldering Temperature
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 50mA
 Reverse Voltage _____ 6V
 Power Dissipation _____ 70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}
 IS5, ISD5, ISQ5 _____ 70V
 IS1, ISD1, ISQ1, IS74, ISD74, ISQ74 _____ 50V
 Emitter-collector Voltage BV_{ECO} _____ 6V
 Collector Current _____ 50mA
 Power Dissipation _____ 150mW

POWER DISSIPATION

Total Power Dissipation _____ 170mW
 (derate linearly 2.67mW/°C above 25°C)

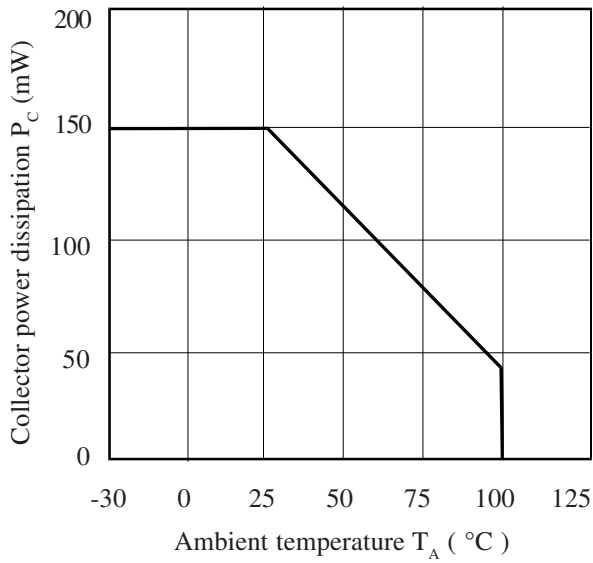
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.65	V	$I_F = 50\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 4\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) IS5, ISD5, ISQ5	70			V	$I_C = 1\text{mA}$
	IS1, ISD1, ISQ1, IS74, ISD74, ISQ74	50			V	(Note 2)
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO})			50	nA	$V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) (Note 2)					
	IS1, ISD1, ISQ1	20		300	%	10mA I_F , 10V V_{CE}
	IS5, ISD5, ISQ5	50		400	%	10mA I_F , 10V V_{CE}
	IS74, ISD74, ISQ74	12.5			%	16mA I_F , 5V V_{CE}
	Saturated Current Transfer Ratio					
	IS1, ISD1, ISQ1		75		%	10mA I_F , 0.4V V_{CE}
	IS5, ISD5, ISQ5		100		%	10mA I_F , 0.4V V_{CE}
	IS74, ISD74, ISQ74		12.5		%	16mA I_F , 0.5V V_{CE}
	Input to Output Isolation Voltage V_{ISO}	5300				V_{RMS} See note 1
	Input to Output Isolation Voltage V_{ISO}	7500				V_{PK} See note 1
Input-output Isolation Resistance R_{ISO}	5×10^{10}				Ω $V_{IO} = 500\text{V}$ (note 1)	
Output Rise Time tr		2.6			μs $I_F = 5\text{mA}$	
Output Fall Time tf		2.2			μs $V_{CC} = 5\text{V}$, $R_L = 75\Omega$	

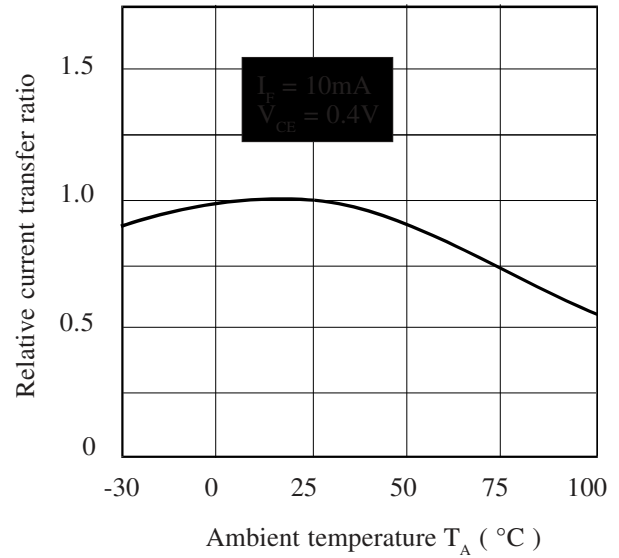
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

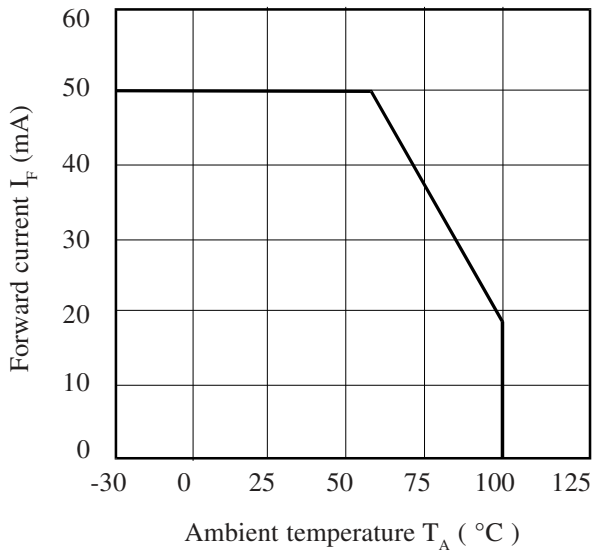
Collector Power Dissipation vs. Ambient Temperature



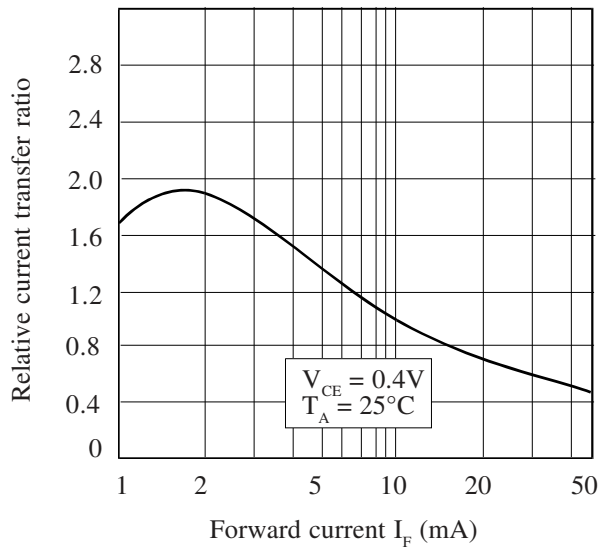
Relative Current Transfer Ratio vs. Ambient Temperature



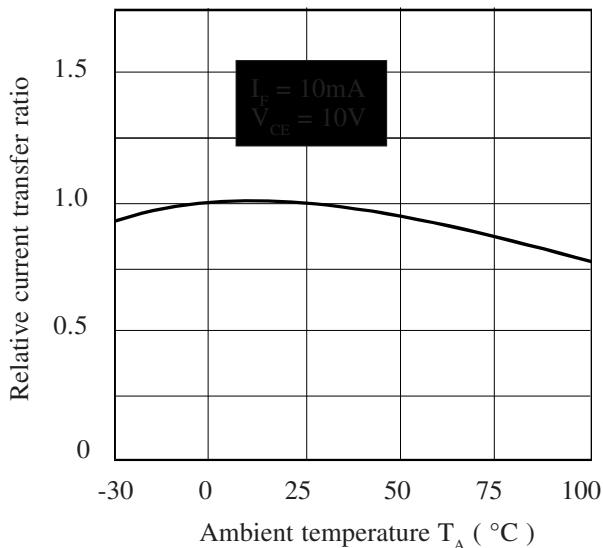
Forward Current vs. Ambient Temperature



Relative Current Transfer Ratio vs. Forward Current



Relative Current Transfer Ratio vs. Ambient Temperature



Relative Current Transfer Ratio vs. Forward Current

